



# CMD225C3

Passive Frequency Doubler, 4-8 GHz Input

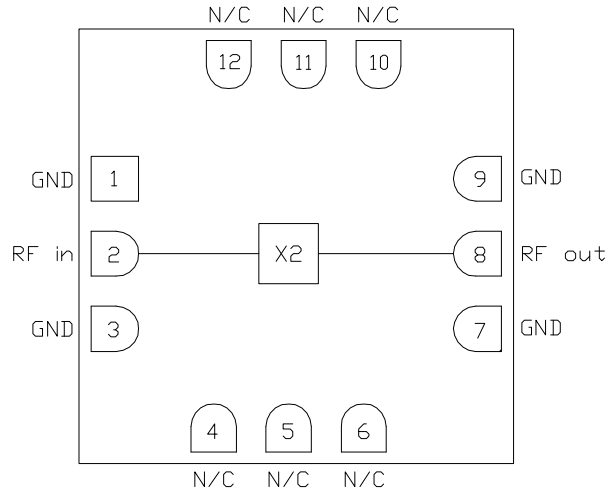
## Features

- ▶ Low conversion loss
- ▶ Excellent Fo isolation
- ▶ Broadband performance
- ▶ No bias required
- ▶ Pb-free RoHs compliant 3x3 mm SMT package

## Description

The CMD225C3 die is a broadband MMIC GaAs x2 passive frequency multiplier housed in a leadless surface mount package. When driven by a +15 dBm signal, the multiplier provides 13 dB conversion loss at an output frequency of 12 GHz. The Fo and 3Fo isolations are >47 dBc and >54 dBc respectively. The CMD225C3 is a 50 ohm matched design eliminating the need for RF port matching.

## Functional Block Diagram



## Electrical Performance - $T_A = 25\text{ }^\circ\text{C}$ , $P_{in} = +15\text{ dBm}$ , $F_{in} = 6\text{ GHz}$

Parameter	Min	Typ	Max	Units
Frequency Range, Input	4 - 8			GHz
Frequency Range, Output	8 - 16			GHz
Conversion Loss		13		dB
Fo Isolation (with respect to input level)		47		dB
3Fo Isolation (with respect to input level)		54		dB
4Fo Isolation (with respect to input level)		50		dB

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## Specifications

### Absolute Maximum Ratings

Parameter	Rating
RF Input Power	+27 dBm
Operating Temperature	-55 to 85 °C
Storage Temperature	-55 to 150 °C

Operation of this device outside the maximum ratings may cause permanent damage.

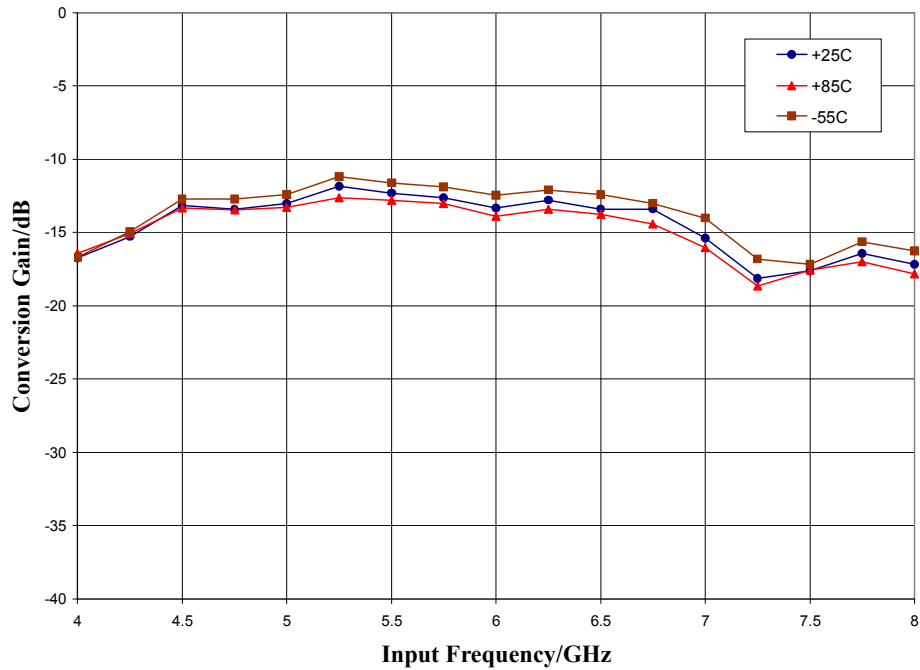
### Electrical Specifications - $T_A = 25\text{ °C}$ , $P_{in} = +15\text{ dBm}$

Parameter	Min	Typ	Max	Min	Typ	Max	Units
Frequency Range, Input	4 - 8			5 - 7			GHz
Frequency Range, Output	8 - 16			10 - 14			GHz
Conversion Loss		13	20		13	17	dB
Fo Isolation (with respect to input level)	33	48		38	48		dB
3Fo Isolation (with respect to input level)	41	50		41	50		dB
4Fo Isolation (with respect to input level)	23	50		33	50		dB

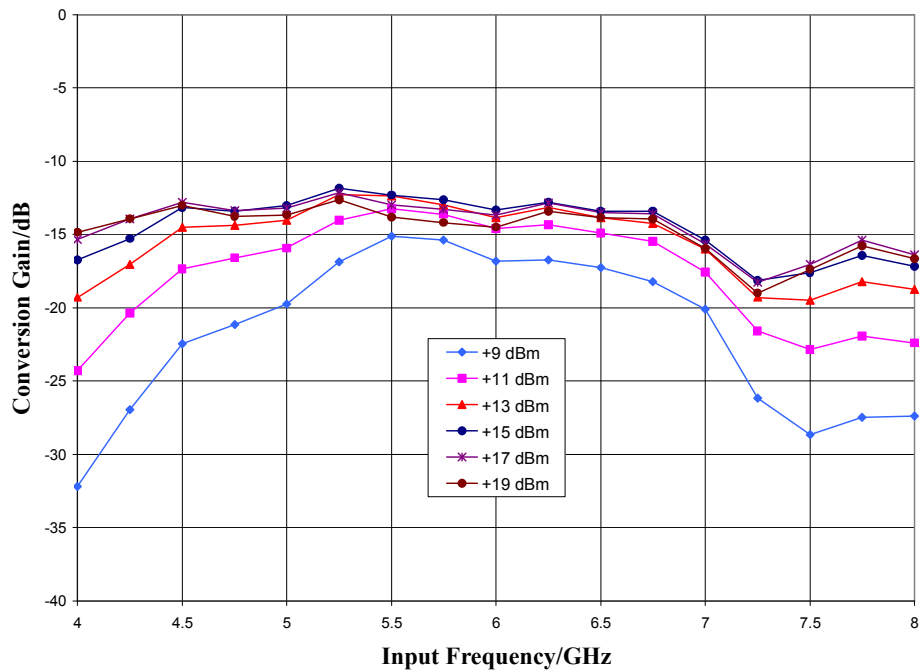
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*Typical Performance*

**Conversion Gain vs. Temperature @ +15 dBm Drive Level**



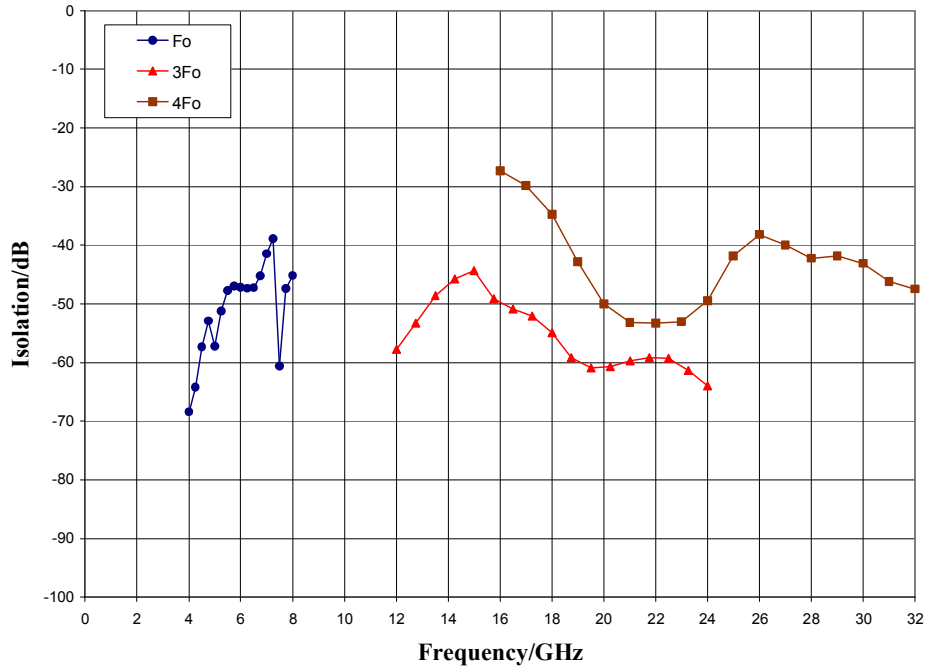
**Conversion Gain vs. Drive Level,  $T_A = 25\text{ }^\circ\text{C}$**



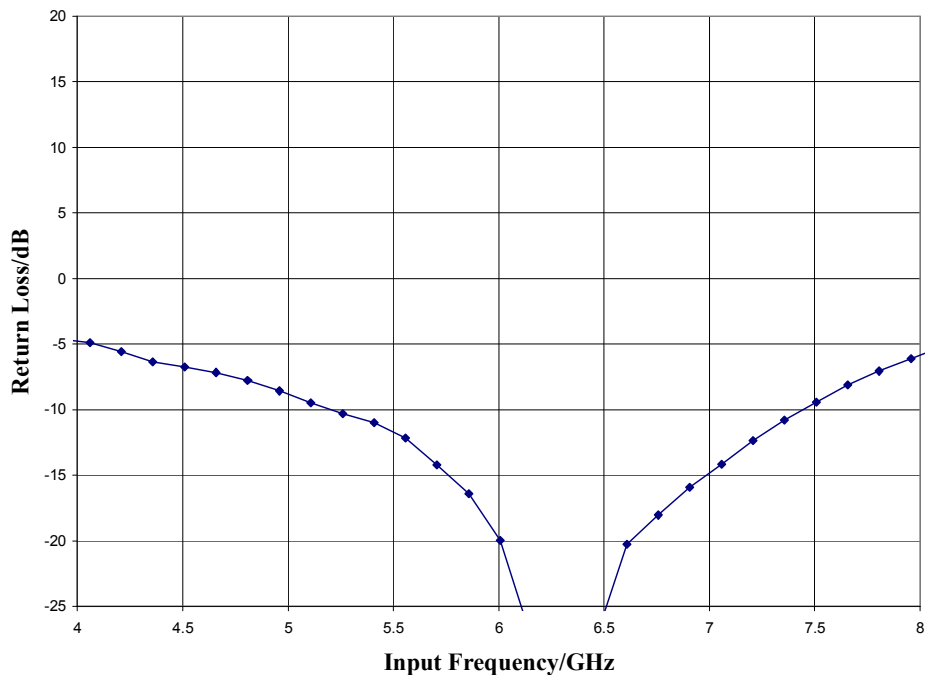
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*Typical Performance*

**Isolation (with respect to input level) @ +15 dBm Drive Level,  $T_A = 25\text{ }^\circ\text{C}$**



**Input Return Loss @ +15 dBm Drive Level,  $T_A = 25\text{ }^\circ\text{C}$**



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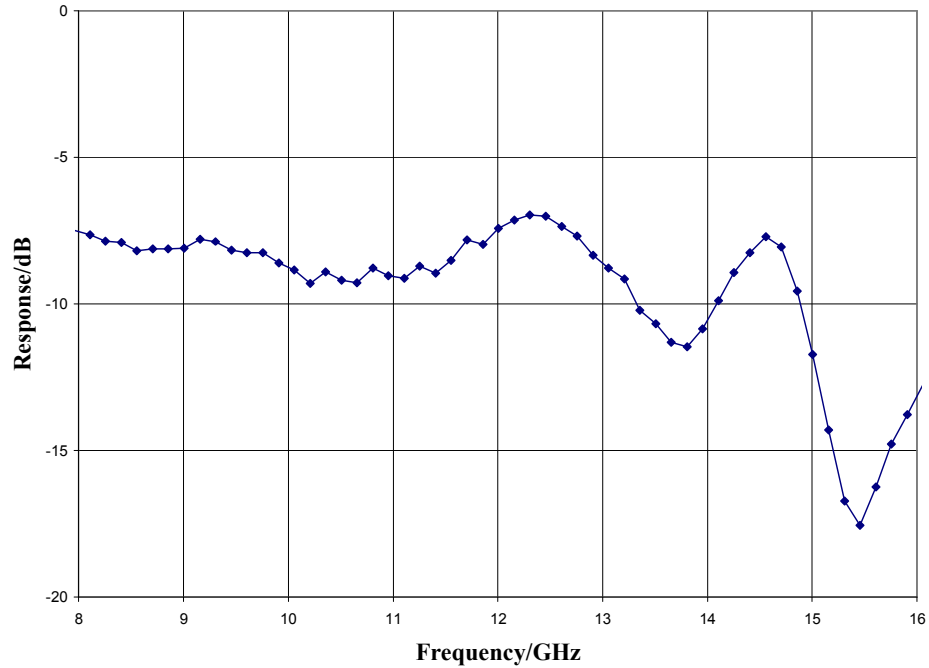


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## Typical Performance

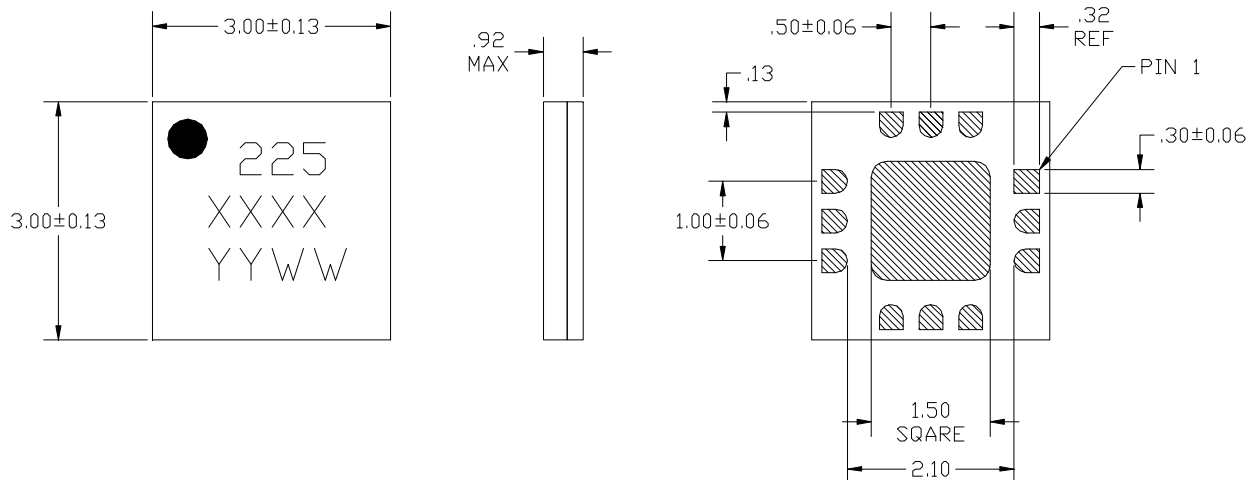
Output Return Loss @ +15 dBm Drive Level, F = 6 GHz Input, T<sub>A</sub> = 25 °C



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## Mechanical Information

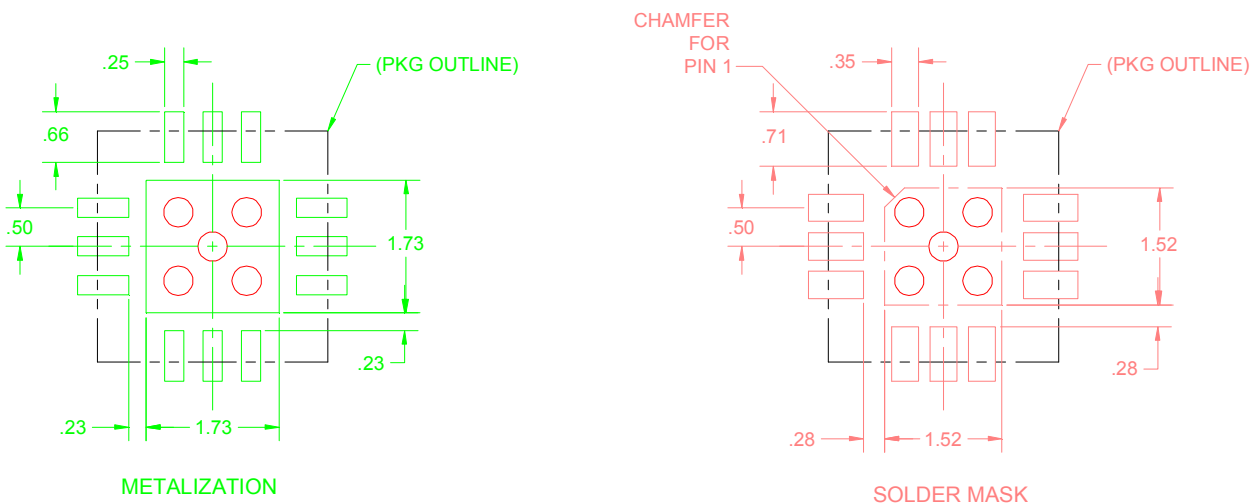
### Package Information and Dimensions



**NOTES:**

1. DIMENSIONS ARE IN MILLIMETERS
2. MATERIAL: BLACK ALUMINA
3. LEAD FINISH: 30-80 MICRONS GOLD OVER 50 MICRONS NICKEL.
4. ALTERNATE PIN #1 IDENTIFIER IS SINGLE SQUARE PAD.

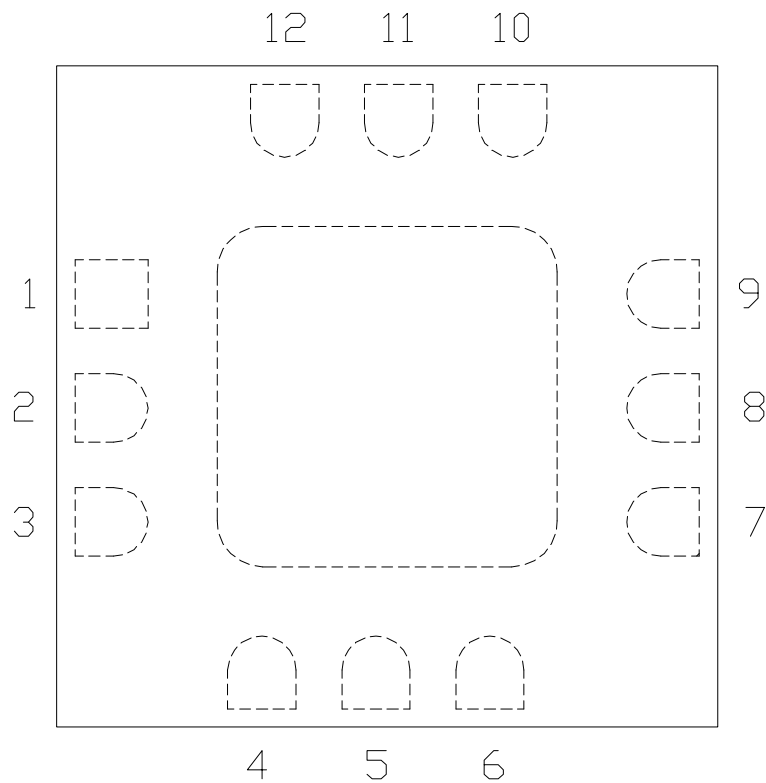
### Recommended PCB Land Pattern






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## Pin Description

### Pin Diagram



### Functional Description

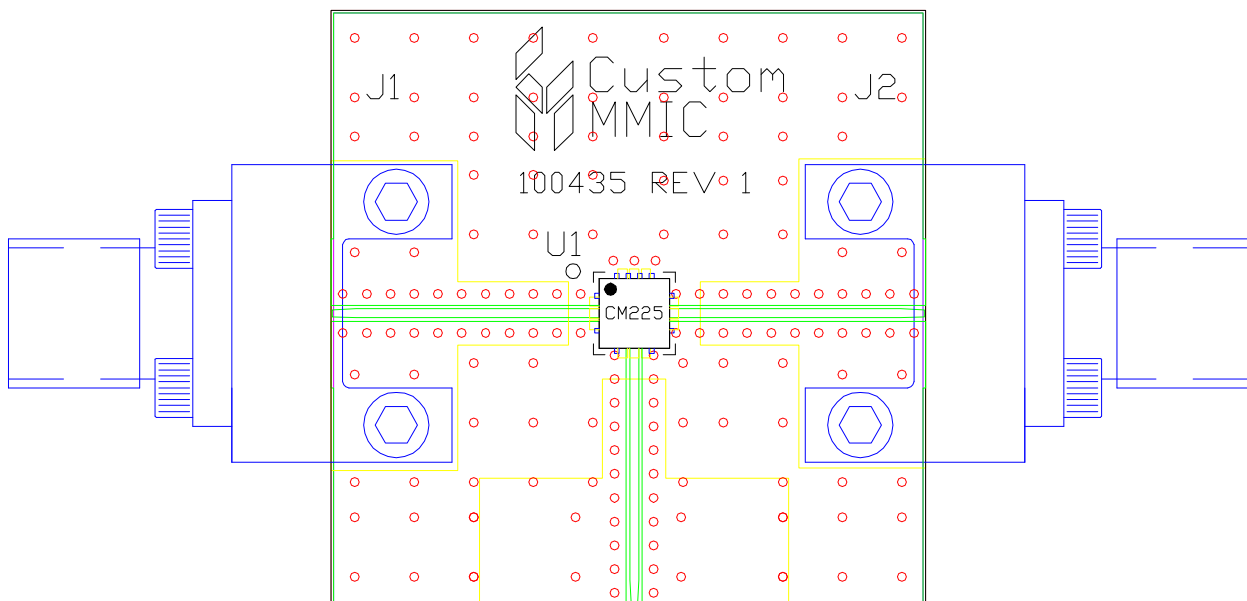
Pad	Function	Description	Schematic
1, 3, 7, 9 and die paddle	Ground	Connect to RF / DC ground	
2	RF in	Pin is DC coupled and 50 ohm matched	
4-6, 10-12	N/C	No connection required. These pins may be connected to RF/DC ground	
8	RF out	Pin is DC coupled and 50 ohm matched	

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### Applications Information

#### Evaluation Board

The circuit board shown has been developed for optimized assembly at Custom MMIC. A sufficient number of via holes should be used to connect the top and bottom ground planes. As surface mount processes vary, careful process development is recommended.



#### Bill of Material

Designator	Value	Description
J1 - J2		SMA End Launch Connector
U1		CMD225C3 Frequency Doubler
PCB		100435 Evaluation PCB

**GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.**

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